DATA SHEET

74LV4052

Dual 4-channel analog multiplexer/demultiplexer

Product specification Supersedes data of 1997 Jul 15 IC24 Data Handbook 1998 Jun 23

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw





Dual 4-channel analog multiplexer/demultiplexer

74LV4052

FEATURES

- Optimized for low voltage applications: 1.0 to 6.0 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Low typ "ON" resistance: 60 Ω at V_{cc} – V_{EE} = 4.5 V 90 Ω at V_{cc} – V_{EE} = 3.0 V 145 Ω at $V_{cc} - V_{EE} = 2.0 \text{ V}$
- Logic level translation: to enable 3 V logic to communicate with \pm 3 V analog signals
- Typical "break before make" built in
- Analog/Digital multiplexing and demultiplexing
- Signal gating
- Output capability: non-standard
- I_{CC} category: MSI

DESCRIPTION

The 74LV4052 is a low-voltage CMOS device and is pin and function compatible with the 74HC/HCT4052.

The 74LV4052 is a dual 4-channel analog multiplexer/demultiplexer with a common select logic. Each multiplexer has four independent inputs/outputs (nY₀ to nY₃) and a common input/output (nZ). The common channel select logics include two digital select inputs (S₀ and S_1) and an active LOW enable input (\overline{E}).

With E LOW, one of the four switches is selected (low impedance ON-state) by S_0 and S_1 . With \overline{E} HIGH, all switches are in the high impedance OFF-state, independent of S_0 and S_1 . V_{CC} and GND are the supply voltage pins for the digital control inputs $(S_0, S_1 \text{ and } \overline{E})$. The V_{CC} to GND ranges are 1.0 to 6.0 V. The analog inputs/outputs (nY₀, to nY₃, and nZ) can swing between V_{CC} as a positive limit and V_{EE} as a negative limit. V_{CC} - V_{EE} may not exceed 6.0 V. For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to GND (typically ground).

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PZH} /t _{PZL}	Turn "ON" time E or V _{OS} S _n	$C_L = 15 \text{ pF}$ $R_L = 1K\Omega$	30	N no
t _{PHZ} /t _{PLZ}	Turn "OFF" time E or V _{OS} S _n	$V_{CC} = 3.3 \text{ V}$	22	ns
CI	Input capacitance	21 100 1. CM. IV.	3.5	
C _{PD}	Power dissipation capacitance per switch	See Notes 1 and 2	57	pF
Cs	Maximum switch capacitance independent (Y) common (Z)	MM. TOOX. COM.	5 CO	WILL

NOTES:

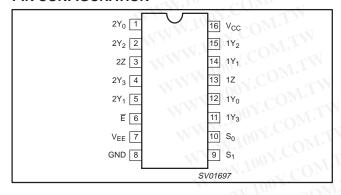
- C_{PD} is used to determine the dynamic power dissipation (P_D in μW)
 - $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum ((C_{L} + C_S) \times V_{CC}^2 \times f_o)$ where:
 - f_i = input frequency in MHz; C_L = output load capacity in pF
 - fo = output frequency in MHz; CS = maximum switch capacitance in pF;

 - V_{CC} = supply voltage in V; $\sum ((C_L + C_S) \times V_{CC}^2 \times f_0)$ = sum of the outputs.
- 2. The condition is $V_I = GND$ to V_{CC} .

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	Code
16-Pin Plastic DIL	-40°C to +125°C	74LV4052 N	74LV4052 N	SOT38-4
16-Pin Plastic SO	-40°C to +125°C	74LV4052 D	74LV4052 D	SOT109-1
16-Pin Plastic SSOP Type II	-40°C to +125°C	74LV4052 DB	74LV4052 DB	SOT338-1
16-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV4052 PW	74LV4052PW DH	SOT403-1

PIN CONFIGURATION



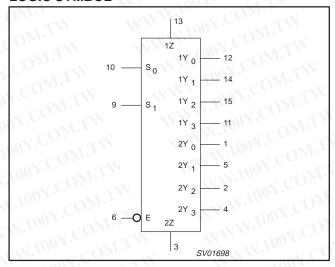
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1, 5, 2, 4	2Y ₀ , 2Y ₃	Independent inputs/outputs
6	E CO	Enable input (active LOW)
7	V _{EE}	Negative supply voltage
8	GND	Ground (0 V)
10, 9	S ₀ , S ₁	Select inputs
12, 14, 15, 11	1Y ₀ to 1Y ₃	Independent inputs/outputs
13, 3	1Z, 2Z	Common inputs/outputs
16	V _{CC}	Positive supply voltage

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LOGIC SYMBOL



FUNCTION TABLE

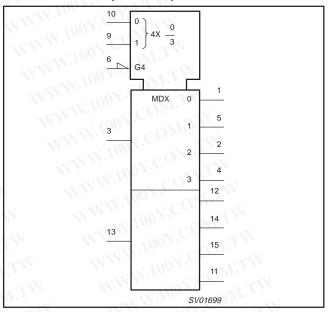
	INPUTS		CHANNEL
E	S ₁	S ₀	ON
L	VAT. COM	TIVL	$nY_0 - nZ$
LWW.	FCO)	Н	$nY_0 - nZ$ $nY_1 - nZ$
L	700 H CO	L	$nY_2 - nZ$
The state of the s	100H	TH	$nY_3 - nZ$

NOTES:

1. H = HIGH voltage level 2. L = LOW voltage level

3. X = don't care

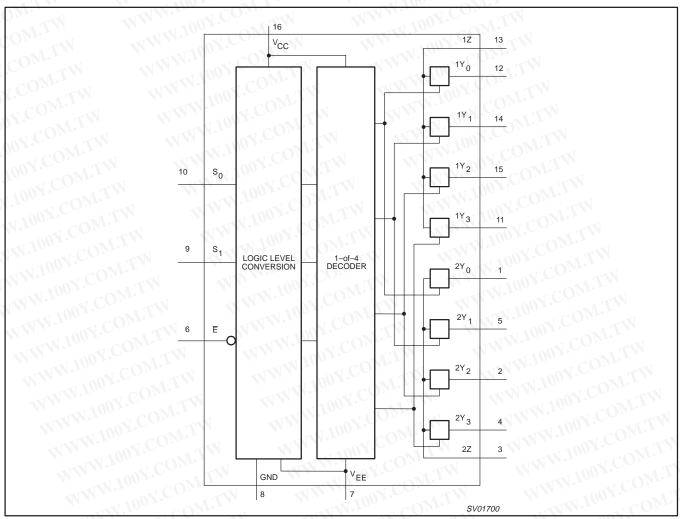
LOGIC SYMBOL (IEEE/IEC)



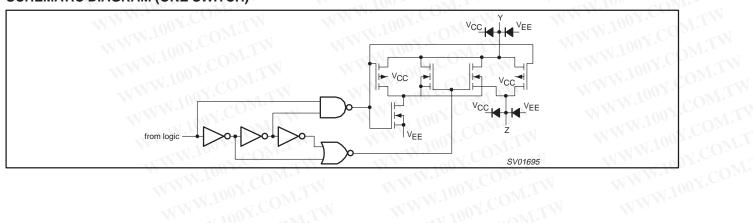
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FUNCTIONAL DIAGRAM



SCHEMATIC DIAGRAM (ONE SWITCH)



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Dual 4-channel analog multiplexer/demultiplexer

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ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134).

Voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
Vcc	DC supply voltage	TIMM Ton COM.	_0.5 to +7.0	V
± I _{IK}	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5 \text{ V}$	20	mA
± I _{SK}	DC switch diode current	$V_S < -0.5 \text{ or } V_S > V_{CC} + 0.5 \text{ V}$	20	mA
±l _S	DC switch current	$-0.5 \text{ V} < \text{V}_{\text{S}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	25	mA
T _{stg}	Storage temperature range	. COM	-65 to +150	°C
P _{TOT}	Power dissipation per package – plastic DIL – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1 and Figure 5	1.0	3.3	6.0	V
VI	Input voltage	OV.COM TW	0		V _{CC}	V
Vo	Output voltage	COM	0	N.1-	Vcc	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40	M.100	+85 +125	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.0 \text{ V to } 2.0 \text{ V}$ $V_{CC} = 2.0 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 2.7 \text{ V to } 6.0 \text{ V}$	- - -	MAT. 10	500 200 100	ns/V

NOTE:

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Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{1.} The LV is guaranteed to function down to $V_{CC} = 1.0V$ (input levels GND or V_{CC}); DC characteristics are guaranteed from $V_{CC} = 1.2V$ to $V_{CC} = 6.0V$.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, voltages are referenced to GND (ground = 0 V)

	1/1/4/	W 100 Y.	J. 11	-TXN .10	Mr.	LIMITS			
SYMBOL	PARAMETER	TEST CO	NDITIONS	-4	0°C to +85	S°C T	-40°C to	+125°C	וואט 🗖
		W. Jun T. COL	VI.	MIN	TYP ¹	MAX	MIN	MAX	7
	14	V _{CC} = 1.2 V	W.I.	0.9	100.	COM	0.9		\top
	W. W.	V _{CC} = 2.0 V	WILL	1.4	1007		1.4		7
VIH	HIGH level Input voltage	$V_{CC} = 2.7 \text{ to } 3.6 \text{ V}$	OM	2.0		COE	2.0		7 ∨
	Vollago	V _{CC} = 4.5 V	OM.	3.15	M.Inc	-1 CON	3.15		7
	WTD	$V_{CC} = 6.0 \text{ V}$	TILL	4.20	-x1 10	17.	4.20		7
N C		V _{CC} = 1.2 V	COL	W	11 11	0.3	WTD	0.3	Т
	L OW I would never	V _{CC} = 2.0 V	COM		N.V.	0.6	Mr.	0.6	1
V_{IL}	LOW level Input voltage	$V_{CC} = 2.7 \text{ to } 3.6 \text{ V}$	Y.C. ONLIN		TXN.	0.8	Mil	0.8	7 ∨
	Vollago	V _{CC} = 4.5 V	OY.CO. TW	<	A NA	1.35	-117	1.35	1
	COM.	$V_{CC} = 6.0 \text{ V}$	COM		TWW	1.80	COL	1.80	7
ñ1007	Input leakage	$V_{CC} = 3.6$	V _I = V _{CC} or GND		- 1	1.0	COM.	1.0	μА
// Til	current	$V_{CC} = 6.0$	Al = ACC OLGIAD		111 11	2.0		2.0	7 μ
Mira	Analog switch	V _{CC} = 3.6	$V_I = V_{IH}$ or V_{IL}	N	WV	1.0	Y.Co.	1.0	T
±ls	OFF-state current per channel	V _{CC} = 6.0	IV _S I = V _{CC} - GND (See Figure 2)	rW	W	2.0	W.Con	2.0	– μΑ
WW.	Analog switch	V _{CC} = 3.6	$V_I = V_{IH}$ or V_{IL}	TW	1	1.0	on Y.CO	1.0	Τ.
±I _S	ON-state current	V _{CC} = 6.0	IV _S I = V _{CC} - GND (See Figure 3)	TV		2.0	ONY.C	2.0	μA
	Quiescent supply	V _{CC} = 3.6 V	$V_I = V_{CC}$ or GND;			20.0	OOY.C	40	N
lcc	current	V _{CC} = 6.0 V	$V_{IS} = GND \text{ or } V_{CC};$ $V_{OS} = V_{CC} \text{ or } GND$	Ni.	N	40.0	V.MO	80	– μΑ
Δl _{CC}	Additional quiescent supply current per input	V _{CC} = 2.7 to 3.6 V	$V_{I} = V_{CC} - 0.6 \text{ V}$	$co_{M_{*}}$		500	W.100	850	μА
4	AMM.100X.C	V _{CC} = 1.2 V	$V_I = V_{IH} \text{ or } V_{IL};$ $I_S = 100 _{\mu}A;$ $V_{IS} = V_{CC} \text{ to GND}$		TW	1	WW.10	107.CO	
	ON-resistance	V _{CC} = 2.0 V	7110	Y.	145	325	- TAN	375	Jw
R_{ON}	(peak)	$V_{CC} = 2.7 \text{ V}$	$V_{I} = V_{IH} \text{ or } V_{IL};$	NV.CO	90	200	MM	235	Ω
	W. 100	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$	$I_S = 1000 \mu A;$	-1 C(80	180		210	4 0
	WW. 100	V _{CC} = 4.5 V	$V_{IS} = V_{CC}$ to GND	00 2.	60	135		160	100
	MMM	V _{CC} = 6.0 V		LOOY!	55	125	MAN	145	4
	WWW.	V _{CC} = 1.2 V	$V_I = V_{IH} \text{ or } V_{IL};$ $I_S = 100 _{\mu}A;$ $V_{IS} = GND$	N.100Y	225	TW	WW	N. 100	JY.C
	ON-resistance	V _{CC} = 2.0 V		W.100	110	235		270	ر تا
R_{ON}	(rail)	V _{CC} = 2.7 V	$V_I = V_{IH}$ or V_{IL} ;	110	70	145		165	Ω
	-TXN	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$	$I_S = 1000 \mu A;$	MAN	60	130		150	1.00
	N.	V _{CC} = 4.5 V	V _{IS} = GND	I.W.X	45	100	. 1	115	1,00
	WW	V _{CC} = 6.0 V	V WT	A	40	85	1	100	1 10

3. R_{ON} (MAX) data is preliminary.

All typical values are measured at T_{amb} = 25°C.
 At supply voltages approaching 1.2 V, the analog switch ON-resistance becomes extremely non-linear. Therefore, it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.

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DC ELECTRICAL CHARACTERISTICS (Continued)

Mr.	VVV	COM	VID III	1111	ov.CO	LIMITS			T
SYMBOL	PARAMETER	TEST CO	NDITIONS	-4	0°C to +85	5°C	-40°C to	+125°C	TINU
	N WW	M. TOOX.CO.	WIT	MIN	TYP ¹	MAX	MIN	MAX	1
COM	W WY	V _{CC} = 1.2 V	$V_I = V_{IH} \text{ or } V_{IL};$ $I_S = 100 _{\mu}A;$ $V_{IS} = V_{CC}$	MAM	250	COM.T	N		Ω
Mo	ON-resistance	$V_{CC} = 2.0 \text{ V}$	W.		120	320	- 41	370	\top
R _{ON}	(rail)	$V_{CC} = 2.7 \text{ V}$	$V_{I} = V_{IH} \text{ or } V_{IL};$	MAG	75	195	3.4	225	7
	1.1	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$	$I_S = 1000 \mu A;$	TAT V	70	175	TIN	205	Ω
	MIN	V _{CC} = 4.5 V	$V_{IS} = V_{CC}$	77	50	130	1.1	150	7
	TW	$V_{CC} = 6.0 \text{ V}$	CO	11/1	45	120	TIM	135	7
00	OM	V _{CC} = 1.2 V	COM		MA	ov C	TY TY		\top
	Maximum variation	V _{CC} = 2.0 V	T. OM.TW		5	100.	1/1.		7
AD	of ON-resistance	$V_{CC} = 2.7 \text{ V}$	$V_I = V_{IH}$ or V_{IL} ;	1	4	1001	TI	N	\bigcup_{Ω}
ΔR_{ON}	between any two	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$	$V_{IS} = V_{CC}$ to GND		4	.10	COM	αĬ	1 ≌
	channels	V _{CC} = 4.5 V	101.0 WIN		3	x1 100 3	TOM?		7
	COM	$V_{CC} = 6.0 \text{ V}$	Toy Com		2	100	C	CVV	1

NOTES:

- 1. All typical values are measured at $T_{amb} = 25$ °C.
- 2. At supply voltages approaching 1.2 V, the analog switch ON-resistance becomes extremely non-linear. Therefore, it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.
- 3. R_{ON} (MAX) data is preliminary.

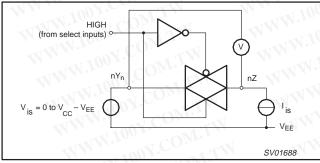


Figure 1. Test circuit for measuring ON-resistance (R_{ON}).

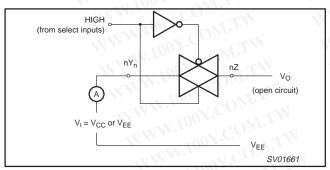


Figure 3. Test circuit for measuring ON-state current.

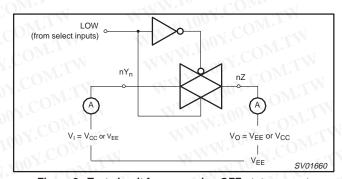


Figure 2. Test circuit for measuring OFF-state current.

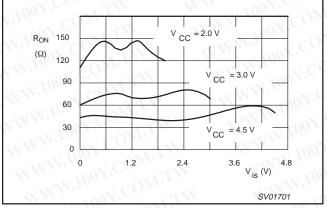


Figure 4. Typical ON-resistance (R_{on}) as a function of input voltage (V_{is}) for V_{is} = 0 to V_{CC} – V_{EE} .

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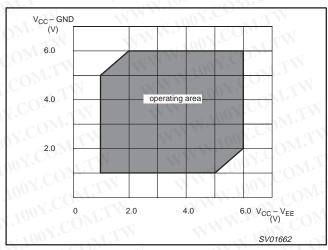


Figure 5. Guaranteed operating area as a function of the supply voltages.

AC CHARACTERISTICS

- W.1	COM	CONDITI	ION OMA			LIMITS	₹ CO	Mr.	J
SYMBOL	PARAMETER	CONDITI	OM	-4	40 to +85	°C	-40 to	+125 °C	UNIT
WWW	100Y.COM.TW	V _{CC} (V)	OTHER	MIN	TYP ¹	MAX	MIN	MAX	Wall.
MAG	1100Y.C M.TW	1.2	M.I	4	25	TIN.	00 7	Mor	1
WW		2.0	R _L = ∞;	W	9	17	1007	20	
	Propagation delay	2.7	$C_L = 50 \text{ pF}$		6	13		15	Negr
t _{PHL} /t _{PLH}	V _{is} to V _{os}	3.0 to 3.6	1110	3,4	5 ²	10	1.100	12	ns
W		4.5	Figure 12	WIL	4	9	- 10	10	
		6.0	V- CO		3	-7	44	8	
	1001. CM.	1.2	7. 100 . CC	Mir	190		MW.T	-1 C	OM.,
		2.0	$R_L = 1k\Omega;$	1.17	65	121		146	
,,	Turn-on time	2.7	$C_L = 50 \text{ pF}$	0,3	48	89 (MAG	108	Co_{Σ}
PZH/tPZL	\overline{E} , S _n to V _{OS}	3.0 to 3.6	Figures 13	-OM.	36 ²	71	TINV	86	ns
		4.5	and 1		32	60	11	73	
		6.0	N N N OUT	.co.,	25	46	MAN	56	
	TAIN 100 C	1.2	MW.	of CO	125	1	-11	11.	ov.CC
		2.0	$R_L = 1k\Omega$:	- 00	43	80	7	95	
, ,	Turn-off time	2.7	$C_L = 50 \text{ pF}$	O.X.C.	33	59	M	71	001.
t _{PHZ} /t _{PLZ}	E, Sn to V _{OS}	3.0 to 3.6	Figures 13	ov.C	26 ²	48	1	57	ns
		4.5	and 1	00.	23	41		49	
		6.0	MM	1007	18	32		38	

NOTES:

2. Typical values are measured at V_{CC} = 3.3 V. WWW.100Y.COM.T

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ADDITIONAL AC CHARACTERISTICS

Recommended conditions and typical values GND = 0 V; $t_r = t_f \le 2.5 ns$

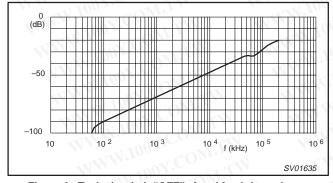
SYMBOL	PARAMETER	TYP.	UNIT	V _{CC} (V)	V _{is(p-p)} (V)	CONDITIONS
COM.	Sine-wave distortion f = 1 kHz	0.80 0.40	%	3.0 6.0	2.75 5.50	R_L = 10 k Ω ; C_L = 50 pf Figure 9 and 10
V.COM	Sine-wave distortion f = 10 kHz	2.40 1.20	%	3.0 6.0	2.75 5.50	$R_L = 10 \text{ k}\Omega$; $C_L = 50 \text{ pf}$ Figure 9 and 10
OA'COL	Switch "OFF" signal feed through	-50 -50	dB	3.0 6.0	Note 1	R_L = 600 Ω ; C_L = 50 pf; f= 1 MHz Figures 5 and 11
OON.CO	Crosstalk between any two switches/multiplexers	-60 -60	dB	3.0 6.0	Note 1	R_L = 600 Ω; C_L = 50 pf; f= 1 MHz Figure 8
V _(p-p)	Crosstalk voltage between enable or address input to any switch (peak-to-peak value)	110 120	mV	3.0 6.0	1	R_L = 600 Ω; C_L = 50 pf; f= 1 MHz (S_n or E , square wave between V_{CC} and GND t_r = t_f = 6 ns) Figure 8
f _{max}	Minimum frequency response (-3 dB)	180 200	MHz	3.0 6.0	Note 2	$R_L = 50 \Omega$; $C_L = 50 pF$ Figures 6, 8 and 9
C _S	Maximum switch capacitance	5	pf	1.1.1		M. 1003. CON. I.

GENERAL NOTES:

- 1. V_{is} is the input voltage at nY or nZ terminal, whichever is assigned as an input.
- 2. V_{OS} is the output voltage at nY or nZ terminal, whichever is assigned as an output.

NOTES:

- 1. Adjust input voltage V_{is} is 0 dBm level (0 dBm = 1 mW into 600 Ω).
- 2. Adjust input voltage V_{is} is 0 dBm level at V_{OS} for 1 MHz (0 dBm = 1 mW into 50 Ω).



5 (dB) 0 10² 10³ 10⁴ f (kHz) 10⁵ 10⁶ SV01636

Figure 6. Typical switch "OFF" signal feed-through as a function of frequency.

Figure 7. Typical frequency response.

NOTES TO FIGURES 6 AND 7:

Test conditions: V_{CC} = 3.0 V; GND = 0 V; V_{EE} = -3.0 V; R_L = 50 Ω ; R_{SOURCE} = 1k Ω .

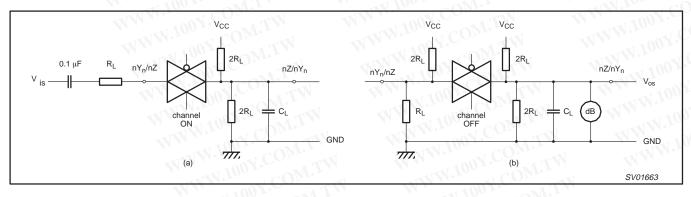


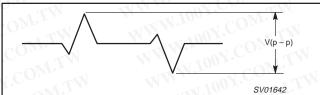
Figure 8. Test circuit for measuring crosstalk between any two switches.
(a) channel ON condition; (b) channel OFF condition.

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NOTE TO FIGURE 8:

The crosstalk is defined as follows (oscilloscope output):



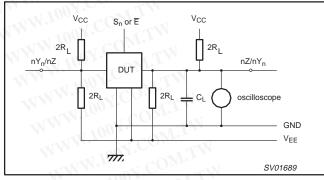


Figure 9. Test circuit for measuring crosstalk between control and any switch.

NOTE TO FIGURE 9:

Adjust input voltage to obtain 0 dBm at V_{OS} when F_{in} = 1 MHz. After set-up frequency of f_{in} is increased to obtain a reading of –3 dB at V_{OS} .

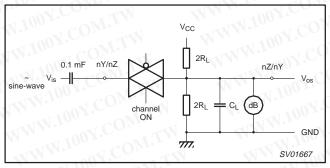


Figure 10. Test circuit for measuring minimum frequency response.

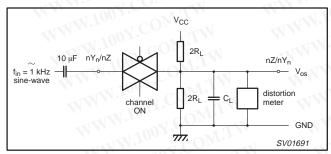


Figure 11. Test circuit for measuring sine-wave distortion.

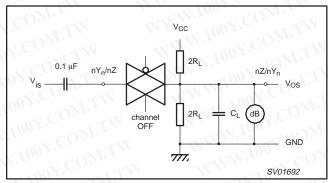


Figure 12. Test circuit for measuring switch "OFF" signal feed-through.

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WAVEFORMS

NOTES:

 $\begin{array}{l} V_M = 1.5 \text{ V at } 2.7 \text{ V} \leq V_{CC} \leq 3.6 \text{ V} \\ V_M = 0.5 \times V_{CC} \text{ at } 2.7 \text{ V} > V_{CC} > 3.6 \text{ V} \end{array}$

 $V_{OL}^{...}$ and $V_{OH}^{}$ are the typical output voltage drop that occur with the output load

 $V_X = V_{OL} + 0.3 \text{ V at } 2.7 \text{ V} \le V_{CC} \le 3.6 \text{ V}$ $V_X = V_{OL} + 0.1 \times V_{CC} \text{ at } 2.7 \text{ V} > V_{CC} > 3.6 \text{ V}$ $V_{\rm Y} = V_{\rm OH} - 0.3 \ V \ {\rm at} \ 2.7 \ V \le V_{\rm CC} \le 3.6 \ V$ $V_{\rm Y} = V_{\rm OH} - 0.1 \times V_{\rm CC} \ {\rm at} \ 2.7 \ V > V_{\rm CC} > 3.6 \ V$

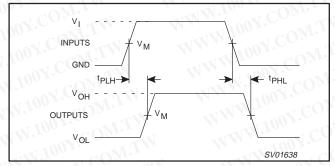


Figure 13. Input (Vis) to output (Vos) propagation delays.

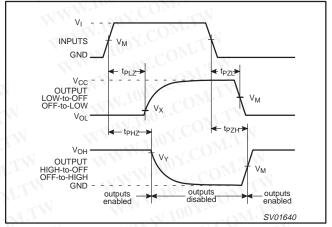


Figure 14. Turn-on and turn-off times for the inputs (S_n, \overline{E}) to the output (V_{os}) .

TEST CIRCUIT

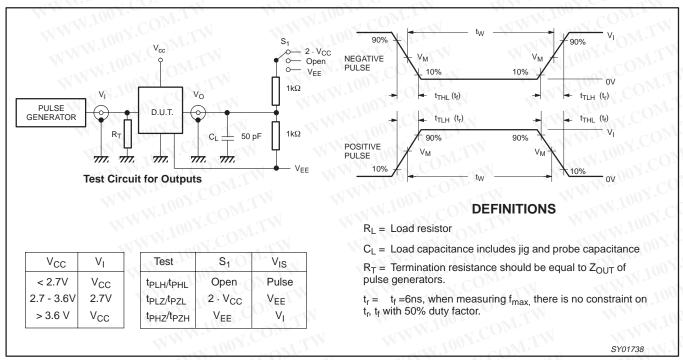
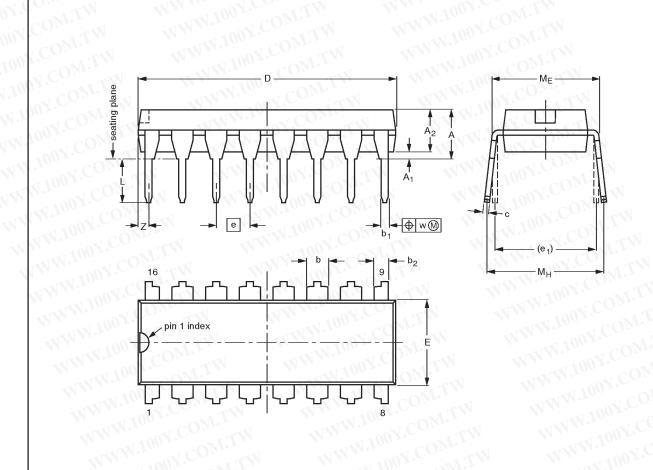


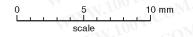
Figure 15. Load circuitry for switching times. WWW.100Y.COM.TW

74LV4052

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4





DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.030

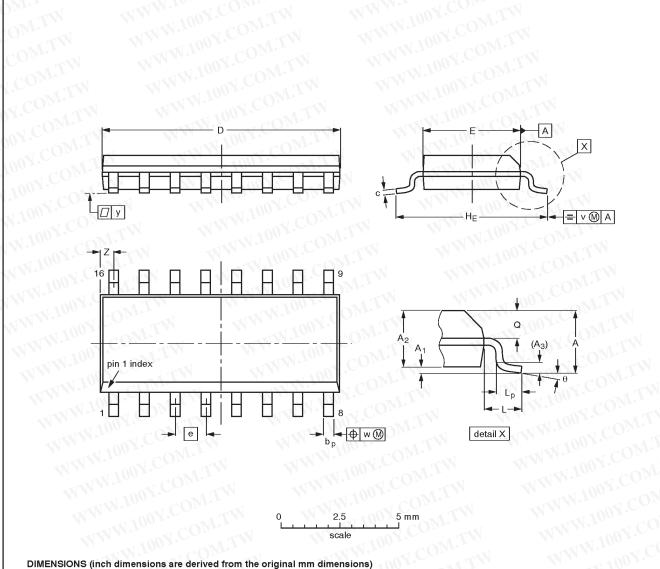
Note

OUTLINE		REFERE	NCES		EUROPEAN	IOOUE DATE
/ERSION	IEC	JEDEC	EIAJ	TANN TOO	PROJECTION	ISSUE DATE
SOT38-4		1007. COM	TIV	MMM.10		92-11-17 95-01-14

74LV4052

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	OLY.	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	100 8°
inches	0.069	0.0098 0.0039		0.01	0.019 0.014	0.0098 0.0075	0.39 0.38	0.16 0.15	0.050	0.24 0.23	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

Note

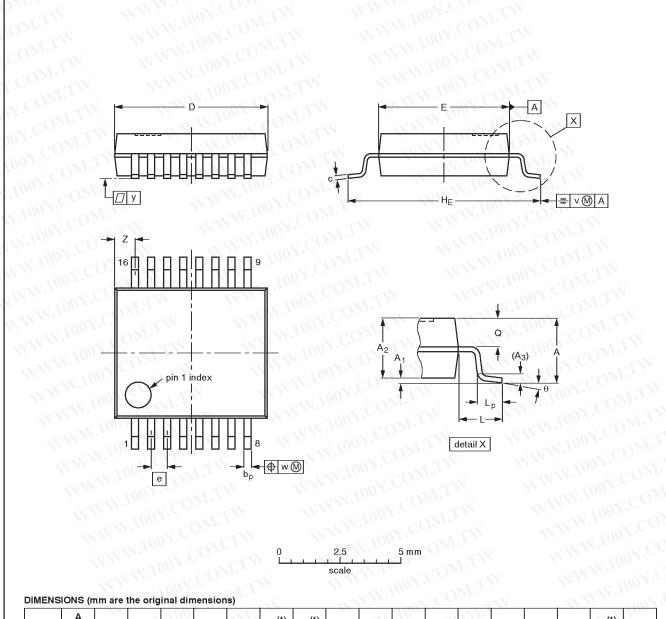
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE	W TIN	REFEI	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	1	PROJECTION	ISSUE DATE
SOT109-1	076E07S	MS-012AC	LTW	WWW		91-08-13 95-01-23

74LV4052

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	C	D ⁽¹⁾	E ⁽¹⁾	е	HE	700	Lp	Q	V	w	У	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

Note

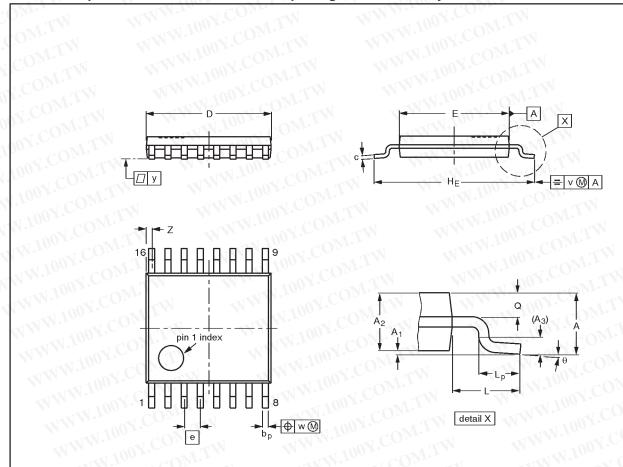
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

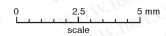
OUTLINE		REFERE	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ	WWW.I	PROJECTION	1330E DATE	
SOT338-1	WWW	MO-150AC		MMM.10		94-01-14 95-02-04	

74LV4052

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1





DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	c	D (1)	E ⁽²⁾	е	HE	750	Lp	Q	V	w	у	Z (1)	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE	MIN.	REFERE	WWW LOOK	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	M. Inc	PROJECTION	ISSUE DATE	
SOT403-1	W	MO-153	TW	M.M.100		94-07-12 95-04-04	

Dual 4-channel analog multiplexer/demultiplexer

74LV4052

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

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